



TP7F54M
TP7F54M(H) **108-cell**
395 - 415W
10BB Half-cut Mono Perc

SYSTEM & PRODUCT CERTIFICATES

- IEC 61215 / IEC 61730 / UL 61730
- ISO 9001: 2015 Quality Management System
- ISO 14001: 2015 Environment Management System
- ISO 45001: 2018 Occupational Health and Safety Management Systems



PERFORMANCE WARRANTY



Linear Performance Warranty

KEY FEATURES



10BB Half-cut Cell Technology

New circuit design, lower internal current, lower Rs loss
Ga doped wafer, attenuation <2% (1st year) / 0.55% (Linear)



Lower LCOE

2% more power generation, lower LCOE



Excellent Anti-PID Performance

2 times of industry standard Anti-PID test



IP68 Junction Box

High waterproof level

ELECTRICAL CHARACTERISTICS

Testing Condition	STC	NMOT	STC	NMOT	STC	NMOT	STC	NMOT	STC	NMOT
Maximum Power (Pmax/W)										
Operating Voltage (Vmpp/V)										
Operating Current (Impp/A)										
Open-Circuit Voltage (Voc/V)										
Short-Circuit Current (Isc/A)										
Module Efficiency (%)	20.20		20.50		20.70		21.00		21.30	

STC: Irradiance 1000W/m², Spectra at AM1.5, Module Temperature 25 °C. Power output tolerance: 0~+5W, Test uncertainty for Pmax: ±3%
NMOT: Irradiance 800W/m², Spectra at AM1.5, Ambient Temperature 20 °C, Wind speed 1m/s

MECHANICAL CHARACTERISTICS

Cell Type	Monocrystalline Silicon (10Busbar)
No. of Cells	108pcs in series (6*18)
Module Dimensions	1722*1134*30mm (67.80*44.65*1.18inches)
Weight	21.5kg (47.4lbs.)
Front Glass	
Frame	Anodized Aluminium Alloy
Junction Box	IP68, 3 Bypass Diodes
Output Cables	4mm ² (IEC), 12AWG(UL) 300mm in Length or Customized Length
Connectors	T01/LJQ-3-CSY/MC4/MC4-EV02

TEMPERATURE CHARACTERISTICS

Temperature Coefficient of Pmax	
Temperature Coefficient of Voc	
Temperature Coefficient of Isc	
Nominal Module Operating Temperature (TNO)	

(1) T0.38 0 Td(C) To 29 at 1s (NO.05) 22.4.100684725 -10 T0.526337.05 T0.98/0.721(10) 293.850 0.02450 0.0014 10.539 142.0 (T0.550 14.30 280.10531 t 509 8051 8V8 4.22.1.81. N. 0.2.530844

